## Silicon Epitaxial Planar Switching Diode

## Features

- Fast switching speed
- High reliability


Glass Case DO-35 Dimensions in mm

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Non-Repetitive Peak Reverse Voltage | $V_{\text {RM }}$ | 100 | V |
| Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | 75 | V |
| $\begin{array}{ll}\text { Average Rectified Forward Current } & \text { 1N914 } \\ & \text { 1N914A /B }\end{array}$ | $\mathrm{I}_{\text {F (AV) }}$ | $\begin{gathered} 75 \\ 200 \end{gathered}$ | mA |
| Forward Continuous Current $\begin{aligned} & \text { 1N914 } \\ & \text { 1N914A / B }\end{aligned}$ | FM | $\begin{aligned} & 150 \\ & 300 \end{aligned}$ | mA |
| $\begin{aligned} & \text { Non-Repetitive Peak Forward Surge Current } \quad \begin{array}{l}\text { at } t=1 \mathrm{~s} \\ \text { 1N914 } \\ \text { 1N914A } / \mathrm{B}\end{array}=1 \mu \mathrm{at} \\ & \text { 1N }=1 \mu \mathrm{~s}\end{aligned}$ | $\lambda_{\text {FSM }}$ | $\begin{aligned} & \hline 1 \\ & 1 \\ & 4 \end{aligned}$ | A |
| Power Dissipation | $\mathrm{P}_{\text {tot }}$ | 500 | mW |
| Operating and Storage Temperature Range | $\mathrm{T}_{\mathrm{j}}, \mathrm{T}_{\text {stg }}$ | -65 to +175 | ${ }^{\circ} \mathrm{C}$ |

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter |  | Symbol | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Forward Voltage at $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}$ at $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ at $I_{F}=10 \mathrm{~mA}$ at $I_{F}=20 \mathrm{~mA}$ | 1N914B <br> 1N914B <br> 1N914 <br> 1N914A | $V_{F}$ | $\begin{gathered} 0.62 \\ - \\ - \end{gathered}$ | $\begin{gathered} 0.72 \\ 1 \\ 1 \\ 1 \\ \hline \end{gathered}$ | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } \mathrm{V}_{R}=20 \mathrm{~V} \\ & \text { at } \mathrm{V}_{R}=75 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=20 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \end{aligned}$ |  | $\mathrm{I}_{\mathrm{R}}$ |  | $\begin{gathered} 25 \\ 5 \\ 50 \end{gathered}$ | nA $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| Diode Capacitance at $\mathrm{V}_{\mathrm{R}}=0, \mathrm{f}=1 \mathrm{MHz}$ |  | $\mathrm{C}_{\mathrm{j}}$ | - | 4 | pF |
| Reverse Recovery Time at $I_{F}=10 \mathrm{~mA}$ to $\mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{R}}=6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |  | $\mathrm{trr}_{\text {r }}$ | - | 4 | ns |

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